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[Vishay Semiconductor/Diodes Division](#)
[VS-ST700C12L0](#)

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Phase Control Thyristors (Hockey PUK Version), 910 A



TO-200AC (B-PUK)



RoHS
COMPLIANT

FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

PRODUCT SUMMARY	
Package	TO-200AC (B-PUK)
Diode variation	Single SCR
$I_{T(AV)}$	910 A
V_{DRM}/V_{RRM}	1200 V, 1600 V, 1800 V, 2000 V
V_{TM}	1.80 V
I_{GT}	100 mA
T_J	-40 °C to 125 °C

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		910	A
	T_{hs}	55	°C
$I_{T(RMS)}$		1857	A
	T_{hs}	25	°C
I_{TSM}	50 Hz	15 700	A
	60 Hz	16 400	
I^2t	50 Hz	1232	kA^2s
	60 Hz	1125	
V_{DRM}/V_{RRM}		1200 to 2000	V
t_q	Typical	150	μs
T_J		-40 to 125	°C

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_{J\text{ MAX}}$ mA
VS-ST700CL	12	1200	1300	80
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	



ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS			
Maximum average on-state current at heatsink temperature	$I_{T(AV)}$	180° conduction, half sine wave double side (single side) cooled			910 (355)	A			
					55 (85)	°C			
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 25 °C heatsink temperature double side cooled			1857	A			
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	$t = 10 \text{ ms}$	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	15 700				
		$t = 8.3 \text{ ms}$			16 400				
		$t = 10 \text{ ms}$	100 % V_{RRM} reapplied		13 200				
		$t = 8.3 \text{ ms}$			13 800				
Maximum I^2t for fusing	I^2t	$t = 10 \text{ ms}$	No voltage reapplied		1232	kA ² s			
		$t = 8.3 \text{ ms}$			1125				
		$t = 10 \text{ ms}$	100 % V_{RRM} reapplied		871				
		$t = 8.3 \text{ ms}$			795				
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied			12 321	kA ² √s			
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum			1.00	V			
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum			1.13				
Low level value of on-state slope resistance	r_{t1}	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum			0.40	mΩ			
High level value of on-state slope resistance	r_{t2}	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum			0.35				
Maximum on-state voltage	V_{TM}	$I_{pk} = 2000 \text{ A}$, $T_J = T_J$ maximum, $t_p = 10 \text{ ms}$ sine pulse			1.80	V			
Maximum holding current	I_H	$T_J = 25 \text{ °C}$, anode supply 12 V resistive load			600	mA			
Typical latching current	I_L				1000				

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	$Gate$ drive 20 V, 20 Ω, $t_r \leq 1 \mu\text{s}$ $T_J = T_J$ maximum, anode voltage $\leq 80 \% V_{DRM}$			1000	A/μs
Typical delay time	t_d	$Gate$ current 1 A, $dl_g/dt = 1 \text{ A}/\mu\text{s}$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \text{ °C}$			1.0	μs
Typical turn-off time	t_q	$I_{TM} = 750 \text{ A}$, $T_J = T_J$ maximum, $dl/dt = 60 \text{ A}/\mu\text{s}$, $V_R = 50 \text{ V}$, $dV/dt = 20 \text{ V}/\mu\text{s}$, gate 0 V 100 Ω, $t_p = 500 \mu\text{s}$			150	

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}			500	V/μs
Maximum peak reverse and off-state leakage current	I_{RRM} , I_{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied			80	mA



VS-ST700CL Series

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TRIGGERING		PARAMETER	SYMBOL	TEST CONDITIONS	VALUES		UNITS
Typ.	Max.				Typ.	Max.	
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum, $t_p \leq 5$ ms			10.0		W
Maximum average gate power	$P_{G(AV)}$	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$			2.0		
Maximum peak positive gate current	I_{GM}	$T_J = T_J$ maximum, $t_p \leq 5$ ms			3.0		A
Maximum peak positive gate voltage	$+V_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms			20		V
Maximum peak negative gate voltage	$-V_{GM}$				5.0		
DC gate current required to trigger	I_{GT}	$T_J = -40$ °C		Maximum required gate trigger/current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied	200	-	mA
		$T_J = 25$ °C			100	200	
		$T_J = 125$ °C			50	-	
DC gate voltage required to trigger	V_{GT}	$T_J = -40$ °C		Maximum required gate trigger/current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied	2.5	-	V
		$T_J = 25$ °C			1.8	3.0	
		$T_J = 125$ °C			1.1	-	
DC gate current not to trigger	I_{GD}	$T_J = T_J$ maximum		Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied	10		mA
DC gate voltage not to trigger	V_{GD}				0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction temperature range	T_J			-40 to 125	°C
Maximum storage temperature range	T_{Stg}			-40 to 150	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled		0.073	K/W
		DC operation double side cooled		0.031	
Maximum thermal resistance, case to heatsink	R_{thC-hs}	DC operation single side cooled		0.011	
		DC operation double side cooled		0.006	
Mounting force, ± 10 %				14 700 (1500)	N (kg)
Approximate weight				255	g
Case style		See dimensions - link at the end of datasheet		TO-200AC (B-PUK)	

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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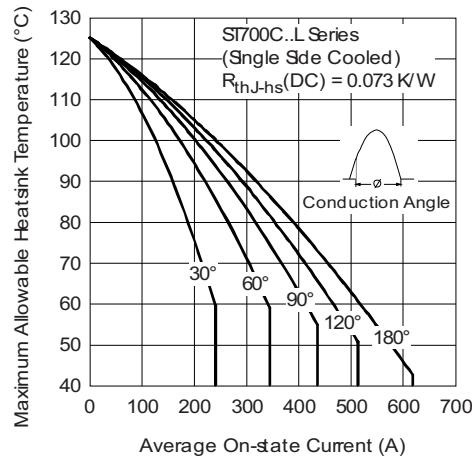


Fig. 1 - Current Ratings Characteristics

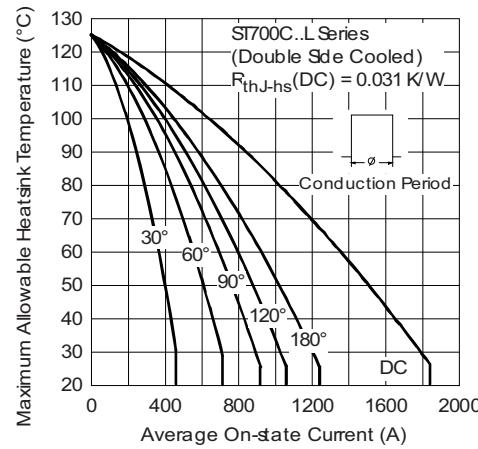


Fig. 4 - Current Ratings Characteristics

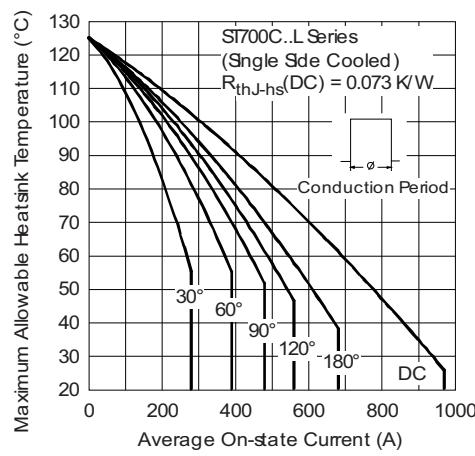


Fig. 2 - Current Ratings Characteristics

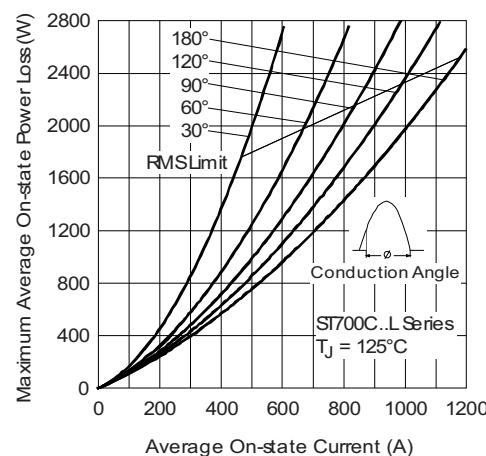


Fig. 5 - On-State Power Loss Characteristics

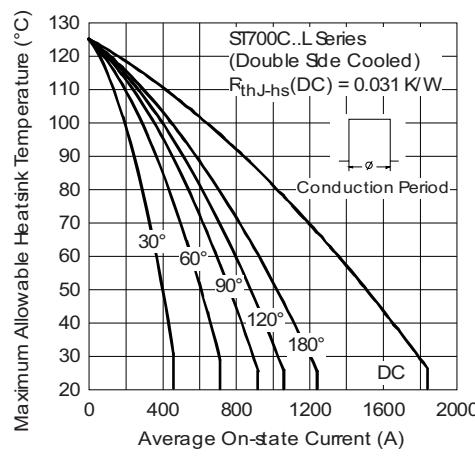


Fig. 3 - Current Ratings Characteristics

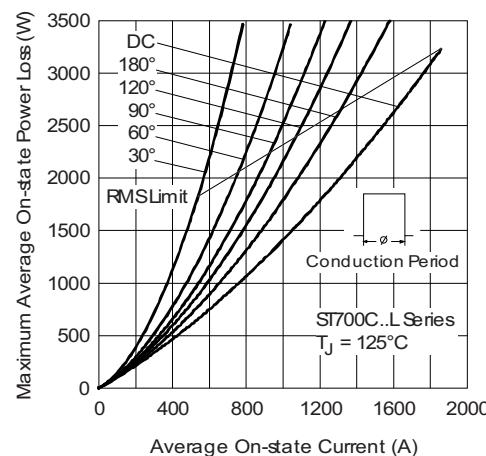


Fig. 6 - On-State Power Loss Characteristics

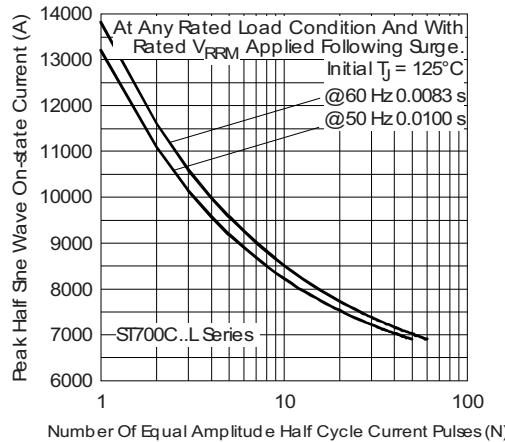


Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

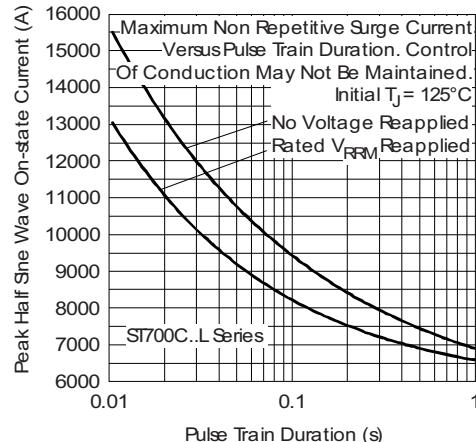


Fig. 8 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

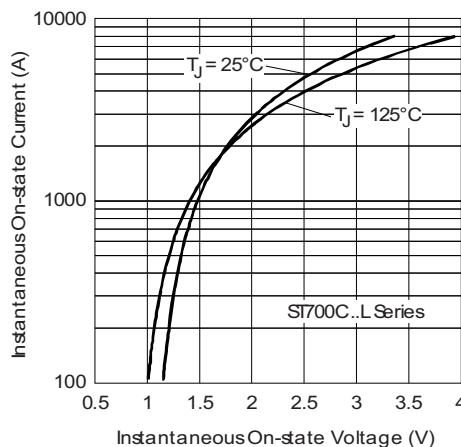


Fig. 9 - On-State Voltage Drop Characteristics

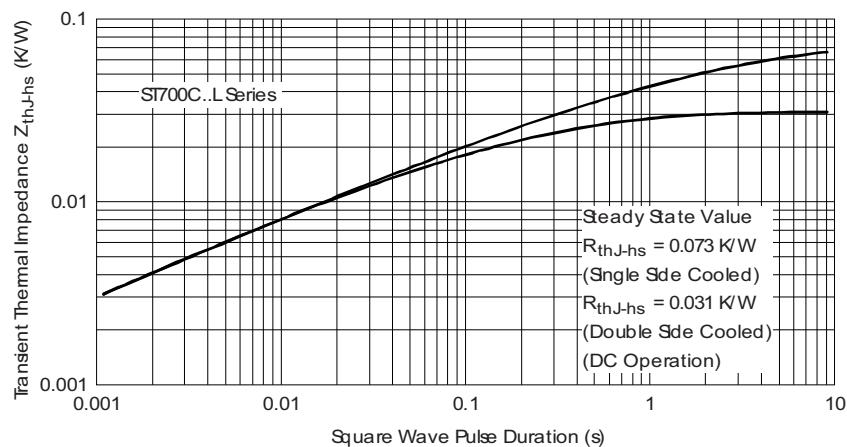


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

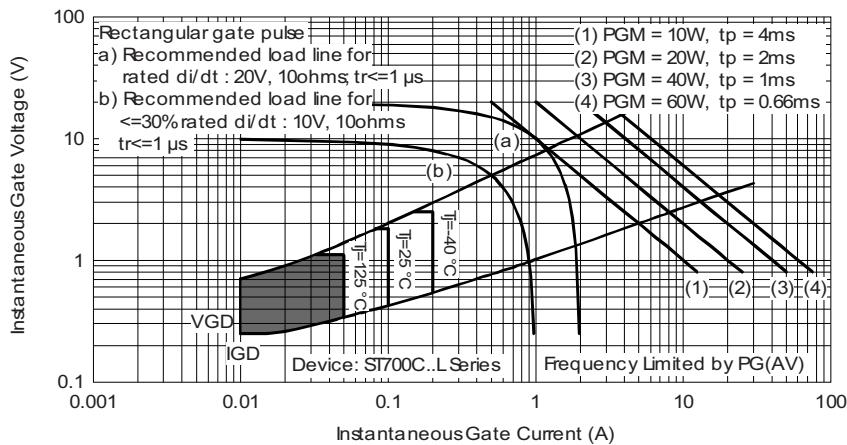


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	ST	70	0	C	20	L	1	-
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

- 1** - Vishay Semiconductors product
- 2** - Thyristor
- 3** - Essential part number
- 4** - 0 = converter grade
- 5** - C = ceramic PUK
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - L = PUK case TO-200AC (B-PUK)
- 8** - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)
 1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)
 2 = eyelet terminals (gate and auxiliary cathode soldered leads)
 3 = fast-on terminals (gate and auxiliary cathode soldered leads)
- 9** - Critical dV/dt : • None = 500 V/ μs (standard selection)
 • L = 1000 V/ μs (special selection)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95076



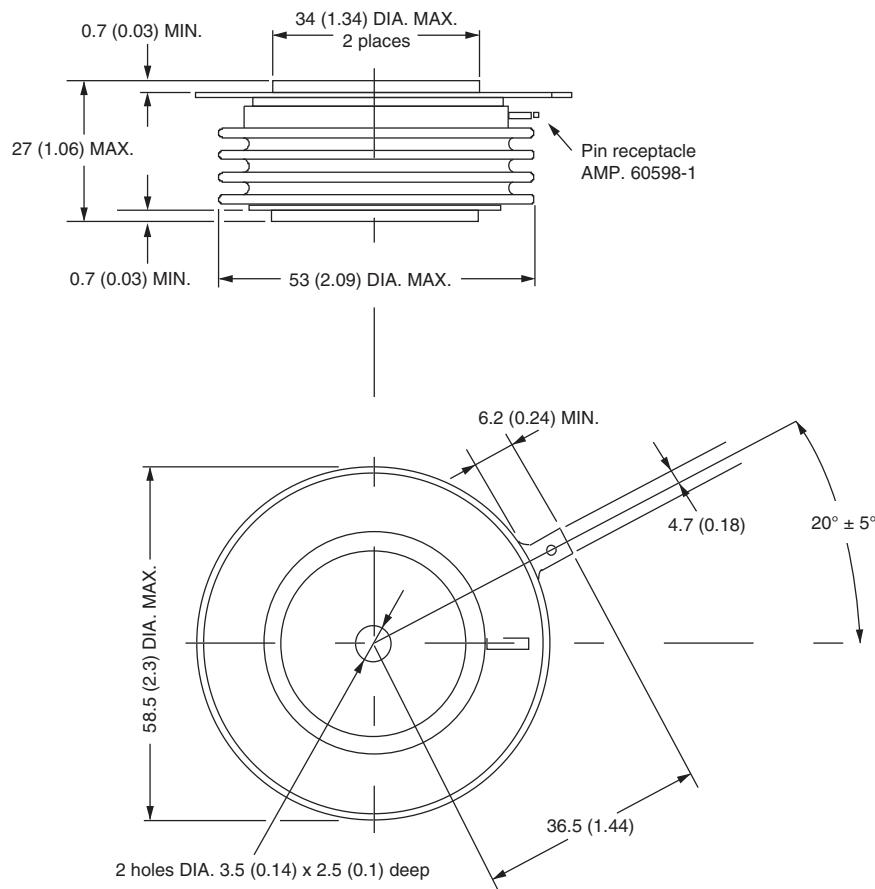
Outline Dimensions

Vishay Semiconductors

TO-200AC (B-PUK)

DIMENSIONS in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum
Strike distance: 17.43 (0.686) minimum





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